## NSN 5961-00-329-8161

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-329-8161 **Inclosure Material:** Glass **Overall Length:** 0.082 inches **Terminal Length:** 0.064 inches **Overall Diameter:** 0.084 inches **End Application:** Aircraft, hornet f/a-18; aircraft, eagle f-15; aircraft, harrier av-8b; missile, air launch cruise (alcm) agm-86b **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 2.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Weapon system essential; junction pattern arrangement: pin **Test Data Document:** 82577-925949 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:**